

1A High-Speed MOSFET Drivers

Features

- Latch-Up Protected: Will Withstand 500 mA Reverse Current
- Input Will Withstand Negative Inputs Up to 5V
- Electrostatic Discharge (ESD) Protected: 2.0 kV (HBM) and 400V (MM)
- · High-Peak Output Current: 1A
- Wide Input Supply Voltage Operating Range:
 - 4.5V to 16V
- · High Capacitive Load Drive Capability:
 - 1000 pF in 25 ns
- · Short Delay Time: 30 ns typical
- · Matched Delay Times
- · Low Supply Current
 - With Logic '1' Input: 500 μA
 - With Logic '0' Input: 100 μA
- Low Output Impedance: 8Ω
- Available in Space-Saving 8-pin MSOP Package
- Pinout same as TC1410/TC1412/TC1413

Applications

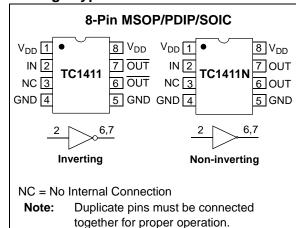
- Switch Mode Power Supplies
- Pulse Transformer Drive
- · Line Drivers
- · Relay Driver

General Description

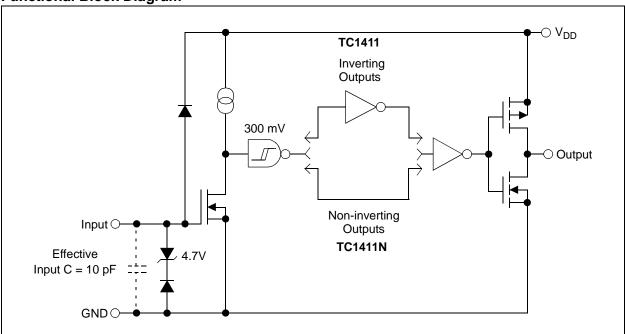
The TC1411/TC1411N are 1A CMOS buffers/drivers. They will not latch up under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking of either polarity occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of current of either polarity being forced back into their output. All terminals are fully protected against Electrostatic Discharge (ESD) up to 2.0 kV (HBM) and 400V (MM).

As MOSFET drivers, the TC1411/TC1411N can easily charge a 1000 pF gate capacitance in 25 ns with matched rise and fall times and provide low enough impedance in both the 'ON' and 'OFF' states to ensure the MOSFET's intended state will not be affected, even by large transients. The leading and trailing edge propagation delay times are also matched to allow driving short-duration inputs with greater accuracy.

Package Types



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage+2	0V
Input Voltage V_{DD} + 0.3V to GND – 5.	0V
Power Dissipation (T _A ≤ 70°C)	
MSOP340 m	٦W
PDIP730 m	าW
SOIC470 m	٦W
Storage Temperature Range65°C to +150	۱°C
Maximum Junction Temperature+150)°C

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, over the operating temperature range with $4.5 \text{V} \le \text{V}_{DD} \le 16 \text{V}$. Typical values are measured at $T_A = +25 \,^{\circ}\text{C}$, $V_{DD} = 16 \text{V}$.

Typical values are measured at $T_A = +25^{\circ}C$, $V_{DD} = 16V$.								
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions		
Input								
Logic '1', High Input Voltage	V_{IH}	2.0	_		V			
Logic '0', Low Input Voltage	V_{IL}	_	_	0.8	V			
Input Current	I _{IN}	-1.0	_	1.0	μA	$0V \le V_{IN} \le V_{DD}, T_A = +25^{\circ}C$		
		-10	_	10		$-40^{\circ}C \le T_A \le +85^{\circ}C$		
Output								
High Output Voltage	V _{OH}	V _{DD} – 0.025	_	_	V	DC Test		
Low Output Voltage	V _{OL}	_	_	0.025	V	DC Test		
Output Resistance	R _O	_	8	11	Ω	$V_{DD} = 16V, I_{O} = 10 \text{ mA},$ $T_{A} = +25^{\circ}\text{C}$		
		_	10	14		$0^{\circ}C \leq T_A \leq +70^{\circ}C$		
			10	14		$-40^{\circ}C \le T_A \le +85^{\circ}C$		
Peak Output Current	I _{PK}	_	1.0	_	Α	V _{DD} = 16V		
Latch-Up Protection Withstand Reverse Current	I _{REV}	_	0.5	_	Α	Duty cycle \leq 2%, t \leq 300 µs, $V_{DD} = 16V$		
Switching Time (Note 1)	•							
Rise Time	t _R	_	25	35	ns	T _A = +25°C		
		_	27	40		$0^{\circ}C \le T_A \le +70^{\circ}C$		
		_	29	40		-40°C ≤ T _A ≤ +85°C, Figure 4-1		
Fall Time	t _F	_	25	35	ns	T _A = +25°C		
			27	40		$0^{\circ}C \le T_A \le +70^{\circ}C$		
		_	29	40		$-40^{\circ}\text{C} \le \text{T}_{A} \le +85^{\circ}\text{C}$, Figure 4-1		
Delay Time	t _{D1}	_	30	40	ns	$T_A = +25$ °C		
		_	33	45		$0^{\circ}C \le T_A \le +70^{\circ}C$		
		_	35	45		-40 °C \leq T _A \leq +85°C, Figure 4-1		
Delay Time	t _{D2}	_	30	40	ns	$T_A = +25$ °C		
		_	33	45		$0^{\circ}C \le T_A \le +70^{\circ}C$		
		_	35	45		-40 °C $\leq T_A \leq +85$ °C, Figure 4-1		

Note 1: Switching times ensured by design.

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise noted, over the operating temperature range with $4.5V \le V_{DD} \le 16V$. Typical values are measured at $T_A = +25$ °C, $V_{DD} = 16V$.

· ·	. /\					
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Power Supply						
Power Supply Current	I _S	_	0.5	1.0	mA	$V_{IN} = 3V$, $V_{DD} = 16V$
		_	0.1	0.15		$V_{IN} = 0V$

Note 1: Switching times ensured by design.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all parameters apply with $4.5V \le V_{DD} \le 16V$.								
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions		
Temperature Ranges								
Specified Temperature Range (C)	T _A	0	_	+70	°C			
Specified Temperature Range (E)	T _A	-40	_	+85	°C			
Specified Temperature Range (V)	T _A	-40	_	+125	°C			
Maximum Junction Temperature	TJ	_	_	+150	°C			
Storage Temperature Range	T _A	-65	_	+150	°C			
Package Thermal Resistances								
Thermal Resistance, 8L-MSOP	θ_{JA}	_	211	_	°C/W			
Thermal Resistance, 8L-PDIP	θ_{JA}	_	89.3	_	°C/W			
Thermal Resistance, 8L-SOIC	θ_{JA}	_	149.5	_	°C/W			

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, over operating temperature range with $4.5V \le V_{DD} \le 16V$.

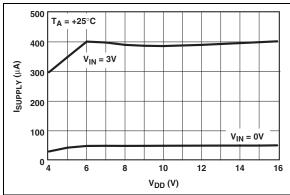


FIGURE 2-1: Quiescent Supply Current vs. Supply Voltage.

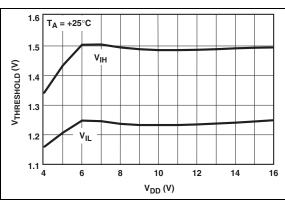


FIGURE 2-2: Input Threshold vs. Supply Voltage.

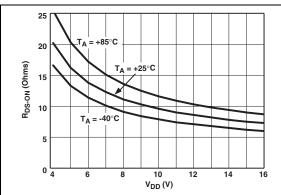


FIGURE 2-3: High-State Output Resistance vs. Supply Voltage.

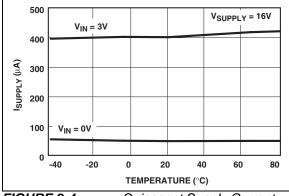


FIGURE 2-4: Quiescent Supply Current vs. Temperature.

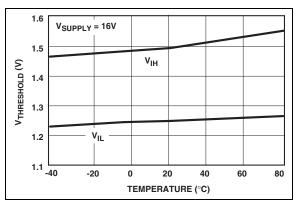


FIGURE 2-5: Input Threshold vs. Temperature.

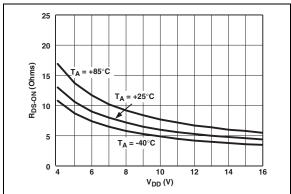


FIGURE 2-6: Low-State Output Resistance vs. Supply Voltage.

Note: Unless otherwise indicated, over operating temperature range with $4.5 \text{V} \le \text{V}_{DD} \le 16 \text{V}$.

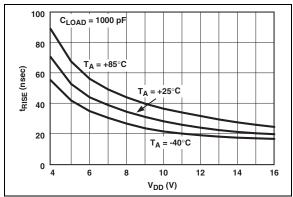


FIGURE 2-7: Voltage.

Rise Time vs. Supply

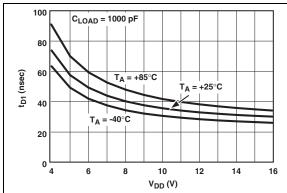


FIGURE 2-8: Supply Voltage.

Propagation Delay vs.

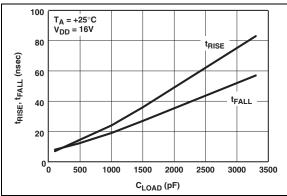


FIGURE 2-9: Capacitive Load.

Rise and Fall Times vs.

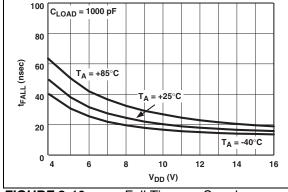


FIGURE 2-10: Voltage.

-10: Fall Time vs. Supply

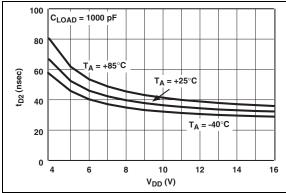


FIGURE 2-11: Supply Voltage.

Propagation Delay vs.

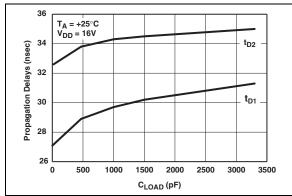


FIGURE 2-12:

Propagation Delays vs.

Capacitive Load.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin No.	TC1411 MSOP, PDIP, SOIC	TC1411N MSOP, PDIP, SOIC	Description		
1	V_{DD}	V_{DD}	Supply input, 4.5V to 16V		
2	IN	IN	Control input		
3	NC	NC	No connection		
4	GND	GND	Ground		
5	GND	GND	Ground		
6	OUT	OUT	CMOS push-pull output, common to pin 7		
7	OUT	OUT	CMOS push-pull output, common to pin 6		
8	V_{DD}	V_{DD}	Supply input, 4.5V to 16V		

3.1 Supply Input (V_{DD})

The V_{DD} input is the bias supply for the MOSFET driver and is rated for 4.5V to 16V with respect to the ground pin. The V_{DD} input should be bypassed to ground with a local ceramic capacitor. The value of the capacitor should be chosen based on the capacitive load that is being driven. A value of 1.0 μ F is suggested.

3.2 Control Input (IN)

The MOSFET driver input is a high-impedance, TTL/CMOS-compatible input. The input has 300 mV of hysteresis between the high and low thresholds that prevents output glitching even when the rise and fall time of the input signal is very slow.

3.3 CMOS Push-pull Output (OUT, OUT)

The MOSFET driver output is a low impedance, CMOS push-pull style output, capable of driving a capacitive load with 1A peak currents.

3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high-peak currents which discharge the load capacitor. The ground pins should be tied into a ground plane or have very short traces to the bias supply source return.

3.5 No Connect (NC)

No internal connection.

4.0 APPLICATION INFORMATION

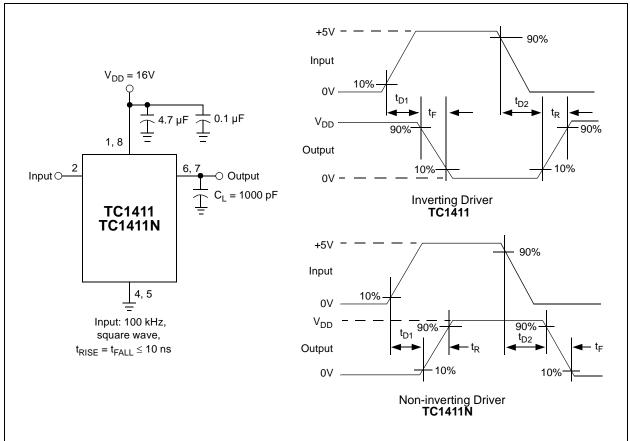
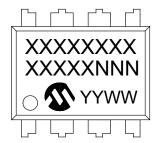


FIGURE 4-1: Switching Time Test Circuit.

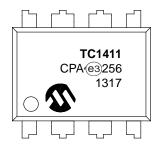
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

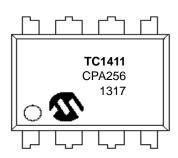
8-Lead PDIP (300 mil)







OR



Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

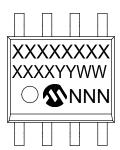
NNN Alphanumeric traceability code

e3 Pb-free JEDEC® designator for Matte Tin (Sn)

* This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

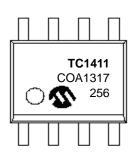
8-Lead SOIC (3.90 mm)



Example



OR



8-Lead MSOP (3x3 mm)

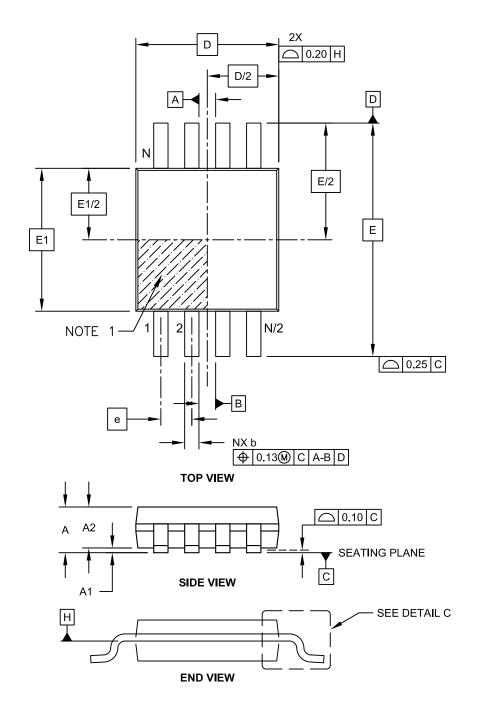


Example



8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

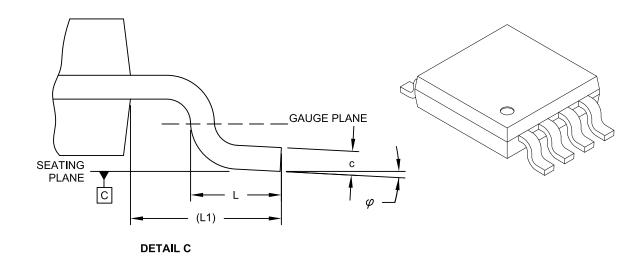
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension Limits		MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		0.65 BSC		
Overall Height	Α	ı	-	1.10	
Molded Package Thickness	A2	0.75	0.85	0.95	
Standoff	A1	0.00	-	0.15	
Overall Width	Е	4.90 BSC			
Molded Package Width	E1	3.00 BSC			
Overall Length	D		3.00 BSC		
Foot Length	L	0.40	0.60	0.80	
Footprint	L1		0.95 REF		
Foot Angle	φ	0° - 8°			
Lead Thickness	С	0.08	-	0.23	
Lead Width	b	0.22	-	0.40	

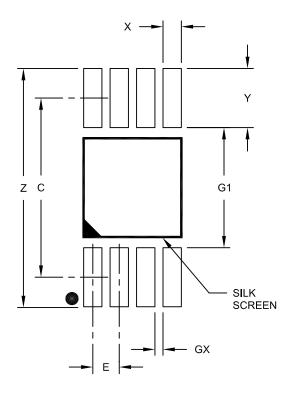
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111C Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	N	ILLIMETER	S	
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	Е	0.65 BSC		
Contact Pad Spacing	C		4.40	
Overall Width	Z			5.85
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G1	2.95		
Distance Between Pads	GX	0.20		

Notes:

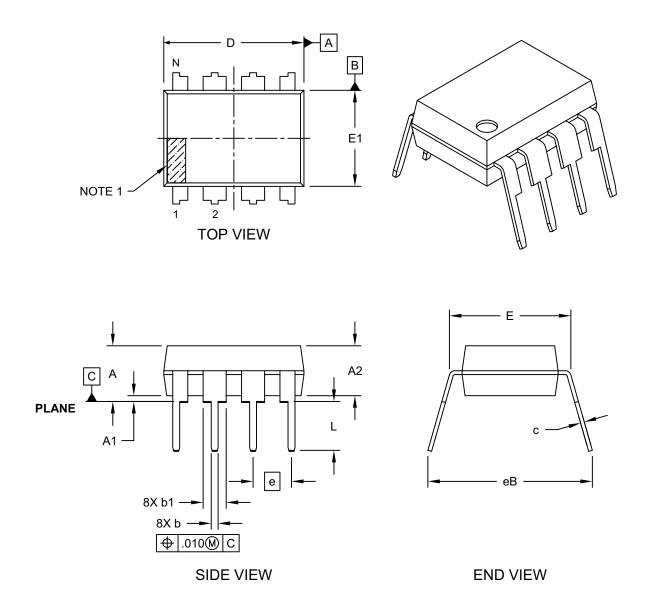
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

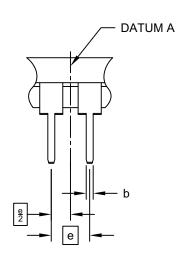
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



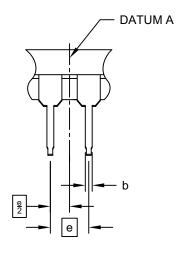
Microchip Technology Drawing No. C04-018D Sheet 1 of 2

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



ALTERNATE LEAD DESIGN (VENDOR DEPENDENT)



	INCHES			
Dimension	MIN	NOM	MAX	
Number of Pins	N		8	
Pitch	е		.100 BSC	
Top to Seating Plane	Α	•	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015		
Shoulder to Shoulder Width	Е	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115 .130 .15		
Lead Thickness	С	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014 .018 .022		
Overall Row Spacing §	eВ	-	-	.430

Notes:

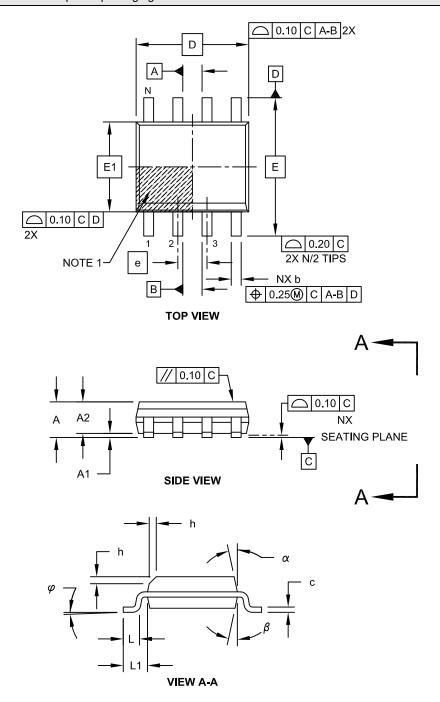
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-018D Sheet 2 of 2 $\,$

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

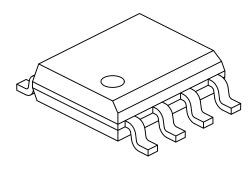
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057C Sheet 1 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		1.27 BSC		
Overall Height	Α	ı	ı	1.75	
Molded Package Thickness	A2	1.25	ı	-	
Standoff §	A1	0.10	ı	0.25	
Overall Width	E	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D		4.90 BSC		
Chamfer (Optional)	h	0.25	ı	0.50	
Foot Length	L	0.40	ı	1.27	
Footprint	L1		1.04 REF		
Foot Angle	φ	0°	ı	8°	
Lead Thickness	С	0.17 - 0.25			
Lead Width	b	0.31	ı	0.51	
Mold Draft Angle Top	α	5° - 15°			
Mold Draft Angle Bottom	β	5°	-	15°	

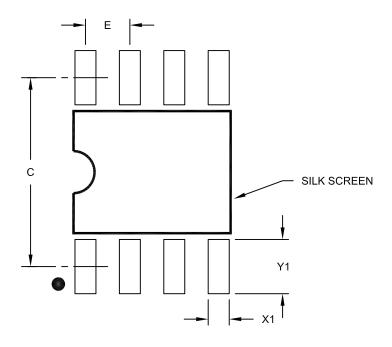
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

lote: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	N	S		
Dimension	Dimension Limits		MIN NOM		
Contact Pitch	E	1.27 BSC			
Contact Pad Spacing	С		5.40		
Contact Pad Width (X8)	X1			0.60	
Contact Pad Length (X8)	Y1			1.55	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

APPENDIX A: REVISION HISTORY

Revision F (February 2015)

The following is the list of modifications:

1. Minor typographical changes.

Revision E (May 2013)

The following is the list of modifications:

- Updated the values for Electrostatic Discharge (ESD) in the Features and General Description columns.
- 2. Updated the Pin Description table in **Section 3.0 "Pin Descriptions"**.

Revision D (September 2006)

- Added -40°C to +125°C temperature range to Temperature Characteristics table and Product Information System page.
- Added disclaimer to package outline drawings.

Revision C (March 2003)

• Added 8-Lead MSOP Package.

Revision B (May 2002)

 Converted TELCOM data sheet for Embedded Control Handbook

Revision A (March 2001)

• Original Release of this Document.

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>(/XX</u>	Exa	Examples:				
 Device Tempo	erature Package nge	a)	TC1411COA:	1A Single MOSFET driver, 8LD SOIC package, 0°C to +70°C.			
Device:	TC1411: 1 A Single MOSFET Driver, Inverting TC1411N: 1 A Single MOSFET Driver, Non-inverting	b)	TC1411CPA:	1A Single MOSFET driver, 8LD PDIP package, 0°C to +70°C.			
Temperature Range:	C = 0°C to +70°C E = -40°C to +85°C V = -40°C to +125°C	c)	TC1411EUA713:	Tape and Reel, 1A Single MOSFET driver, 8LD MSOP package, -40°C to +85°C.			
Package:	OA = Plastic SOIC, (150 mil Body), 8-lead OA713 = Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel) UA = Plastic Micro Small Outline (MSOP), 8-lead * UA713 = Plastic Micro Small Outline (MSOP), 8-lead * (Tape and Reel)	d)	TC1411VOA713:	Tape and Reel, 1A Single MOSFET driver, 8LD SOIC package, -40°C to +125°C.			
	PA = Plastic DIP (300 mil Body), 8-lead * MSOP package is only available in E-Temp.	a)	TC1411NCPA:	1A Single MOSFET driver, 8LD PDIP package, 0°C to +70°C.			
		b)	TC1411NEPA:	1A Single MOSFET driver, 8LD PDIP package, -40°C to +85°C.			
		c)	TC1411NEUA:	1A Single MOSFET driver, 8LD MSOP package, -40°C to +85°C.			
		d)	TC1411NVPA:	1A Single MOSFET driver, 8LD PDIP package, -40°C to +125°C.			

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our
 knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data
 Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, flexPWR, JukeBlox, KEELOQ, KEELOQ logo, Kleer, LANCheck, MediaLB, MOST, MOST logo, MPLAB, OptoLyzer, PIC, PICSTART, PIC³² logo, RightTouch, SpyNIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

The Embedded Control Solutions Company and mTouch are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, ECAN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, KleerNet, KleerNet logo, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, RightTouch logo, REAL ICE, SQI, Serial Quad I/O, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

 $\ensuremath{\mathsf{SQTP}}$ is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademarks of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2001-2015, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-63277-066-0

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199

Tel: 480-792-7200 Fax: 480-792-7277 Technical Support:

http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA

Tel: 678-957-9614 Fax: 678-957-1455

Austin, TX Tel: 512-257-3370

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Novi, MI

Tel: 248-848-4000

Houston, TX Tel: 281-894-5983

Indianapolis
Noblesville, IN

Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles Mission Viejo, CA

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

New York, NY Tel: 631-435-6000

San Jose, CA Tel: 408-735-9110

Canada - Toronto Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office

Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon

Hong Kong

Tel: 852-2943-5100 Fax: 852-2401-3431

Australia - Sydney Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Dongguan Tel: 86-769-8702-9880

China - Hangzhou Tel: 86-571-8792-8115 Fax: 86-571-8792-8116

China - Hong Kong SAR Tel: 852-2943-5100 Fax: 852-2401-3431

China - Nanjing Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao Tel: 86-532-8502-7355

Fax: 86-532-8502-7205 **China - Shanghai** Tel: 86-21-5407-5533

Fax: 86-21-5407-5066 **China - Shenyang** Tel: 86-24-2334-2829

Fax: 86-24-2334-2393
China - Shenzhen

Tel: 86-755-8864-2200 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

ASIA/PACIFIC

China - Xiamen

Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai

Tel: 86-756-3210040 Fax: 86-756-3210049

India - Bangalore Tel: 91-80-3090-4444

Fax: 91-80-3090-4123 India - New Delhi

Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune

Tel: 91-20-3019-1500

Japan - Osaka Tel: 81-6-6152-7160 Fax: 81-6-6152-9310

Japan - Tokyo Tel: 81-3-6880- 3770 Fax: 81-3-6880-3771

Korea - Daegu Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur Tel: 60-3-6201-9857

Fax: 60-3-6201-9859 **Malaysia - Penang** Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila

Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung

Tel: 886-7-213-7828

Taiwan - Taipei Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels

Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen Tel: 45-4450-2828

Fax: 45-4450-2828

France - Paris

Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Dusseldorf Tel: 49-2129-3766400

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Germany - Pforzheim Tel: 49-7231-424750

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Italy - Venice Tel: 39-049-7625286

Netherlands - Drunen Tel: 31-416-690399

Fax: 31-416-690340

Poland - Warsaw Tel: 48-22-3325737

Spain - Madrid

Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Stockholm Tel: 46-8-5090-4654

UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820

01/27/15